HVB14S

Silicon Epitaxial Planar PIN Diode for High Frequency Attenuator

HITACHI

ADE-208-484(Z) Rev 0 December 1996

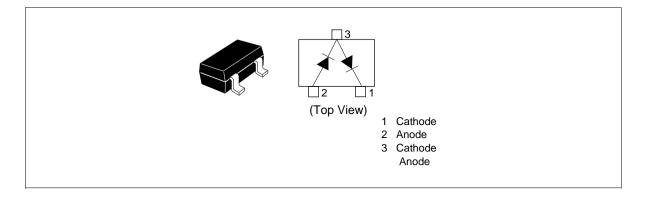
Features

- Low forward resistance. (rf = 7.0Ω max)
- Low capacitance. (C=0.25pF typ)
- CMPAK package is suitable for high density surface mounting and high speed assembly.

Ordering Information

Type No.	Laser Mark	Package Code
HVB14S	H6	CMPAK

Outline





HVB14S

Absolute Maximum Ratings (Ta = 25^{\circ}C)

Item	Symbol	Value	Unit	
Reverse voltage	V_R	50	V	
Forward current	I _F	50	mA	
Power dissipation	P _d *1	100	mW	
Junction temperature	Tj	125	°C	
Storage temperature	Tstg	-55Å`+125	°C	

Note: 1. Two device total.

Electrical Characteristics (Ta = 25° C) *²

Item	Symbol	Min	Тур	Max	Unit	Test Condition
Forward voltage	V_{F}	$\mathring{A} \setminus$	$\mathring{A} \setminus$	1.0	V	$I_F = 50 \text{ mA}$
Reverse current	I _R	Å\	Å\	100	nA	V _R = 50V
Capacitance	С	Å\	0.25	Å\	pF	V _R = 50V, f = 1 MHz
Forward resistance	r _f	Å\	Å\	7	Ω	I _F = 10 mA, f = 100 MHz
ESD-Capability *1	Å\	200	Å\	Å\	V	C=200pF, Both forward and reverse direction 1 pulse

Note: 1. Failure criterion; $I_R \ge 200$ nA at VR =50 V

Note: 2. Per one device.

Main Characteristic

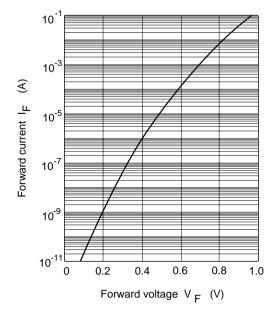


Fig.1 Forward current Vs. Forward voltage

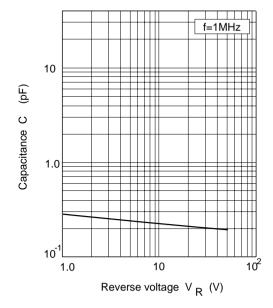


Fig.3 Capacitance Vs. Reverse voltage

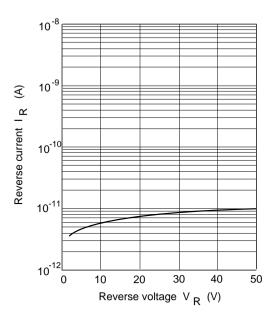


Fig.2 Reverse current Vs. Reverse voltage

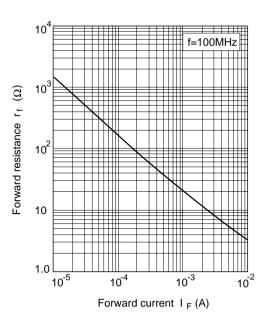
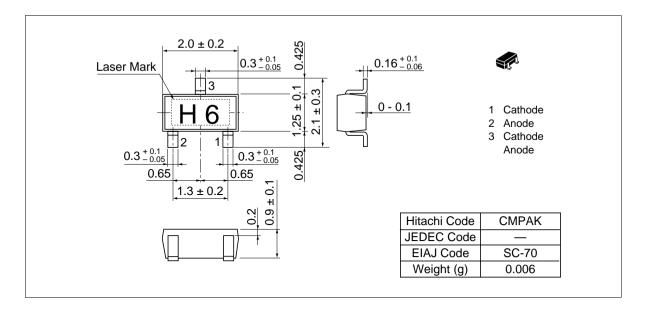


Fig.4 Forward resistance Vs. Forward current

HVB14S

Package Dimensions

Unit: mm



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